## NSN 5961-01-029-7517

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-7517 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 on voltage, forward voltage drop, dc and 65.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 667.0 milliwatts small-signal input power, common-collector preset **Test Data Document:** 10001-2888695 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0